## **ELECTRONIC INFORMATION DISCLOSURE STATEMENT**

Electronic Version v18 Stylesheet Version v18.0

> Title of Invention

SELECTIVE SILICON-ON-INSULATOR ISOLATION STRUCTURE AND METHOD

**Application Number:** 

Confirmation Number:

First Named Applicant: An Steegan Attorney Docket Number: FIS920030051

Search string:

(6429091 or 5153813 or 4849376 or 20020185469).pn.

## **US Patent Documents**

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
	1	6429091	2002-08-06	Chen et al.			
	2	5153813	1992-10-06	Oehrlein et al.			
	3	4849376	1989-07-18	Balzan et al.			

## **US Published Applications**

Note: Applicant is not required to submit a paper copy of cited US Published Applications

init	Cite.No.	Pub. No.	Date	Applicant	Kind	Class	Subclass
	1	20020185469	2002-12-12	Podlesnik et al.			

## Signature

Examiner Name	Date		